General purpose transistor (isolated transistor and diode) QSL10

A 2SD2674 and a RB461F are housed independently in a TSMT5 package.

Applications

DC / DC converter Motor driver

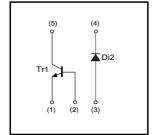
Features

 Tr : Low Vce(sat) Di : Low VF
Small package

Structure

Silicon epitaxial planar transistor Schottky barrier diode

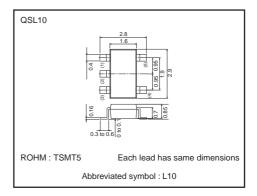
•Equivalent circuit



Packaging specifications

Туре	QSL10
Package	TSMT5
Marking	L10
Code	TR
Basic ordering unit(pieces)	3000

•External dimensions (Unit : mm)



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Transistors

•Absolute maximum ratings (Ta=25°C)

Tr1

Parameter	Symbol	Limits	Unit	
Collector-base voltage	Vсво	15	V	
Collector-emitter voltage	Vceo	12	V	
Emitter-base voltage	Vebo	6	V	
Collector current	lc	1.5	A	
	Іср	3	A *1	
Power dissipation	Pc	0.9	W/ELEMENT *2	
Junction temperature	Tj	150	°C	
Range of storage temperature	Tstg	-40 to +125	°C	

*1 Single pulse, Pw=1ms *2 Mounted on a 25mm×25mm×¹0.8mm ceramic substrate

Di2

Parameter	Symbol	Limits	Unit
Peak reverse voltage	Vrm	25	V
Reverse voltage (DC)	Vr	20	V
Average rectified forward current	lf	700	mA
Forward current surge peak (60Hz, 1∞)	IFSM	3	A
Power dissipation	PD	0.7	W/ELEMENT *
Junction temperature	Tj	125	°C
Range of storage temperature	Tstg	-40 to +125	°C

* Mounted on a 25mm×25mm×10.8mm ceramic substrate

Tr1&Di2

Parameter	Symbol	Limits	Unit
Total power disipation	Da	0.5	W/ELEMENT*1
	P⊳	1.25	W/ELEMENT*2

*1 Each terminal mounted on a recommended land. *2 Mounted on a 25mm×25mm×t0.8mm ceramic substrate.

•Electrical characteristics (Ta=25°C)

Tr1

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Collector-base breakdown voltage	ВУсво	15	-	-	V	Ic=10μA
Collector-emitter breakdown voltage	BVCEO	12	_	-	V	Ic=1mA
Emitter-base breakdown voltage	ВVево	6	_	-	V	Ιε=10μΑ
Collector cutoff current	Ісво	-	-	100	nA	Vcb=15V
Emitter cutoff current	Іево	-	-	100	nA	Veb=6V
Collector-emitter saturation voltage	VCE(sat)	-	85	200	mV	Ic/IB=500mA/25mA
DC current gain	hfe	270	-	680	-	Vce/Ic=2V/200mA *
Transition frequency	f⊤	-	400	-	MHz	Vce=2V, Ie=-200mA, f=100MHz*
Collector output capacitance	Cob	-	12	-	pF	Vcb=10V, Ie=0A, f=1MHz

* Pulsed

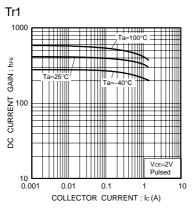
Di2

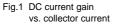
Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Forward voltage	VF	-	450	490	mV	IF=700mA
Reverse current	IR	-	-	200	μA	VR=20V
Reverse recovery fime	trr	-	9	_	ns	IF=IR=100mA, Irr=0.1IR

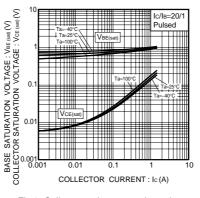
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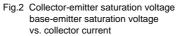
Transistors

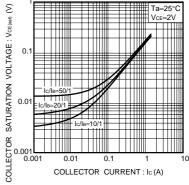
•Electrical characteristic curves

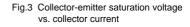


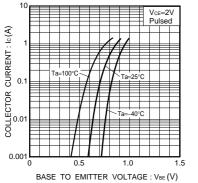


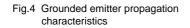


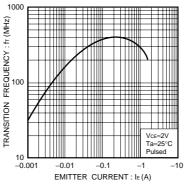


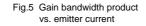


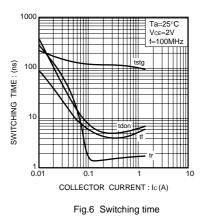


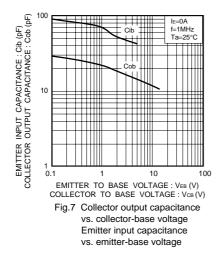








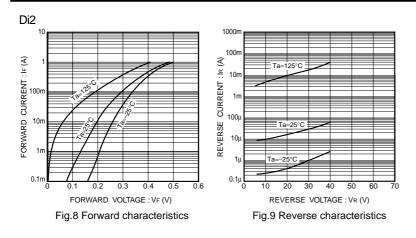




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